MMBT2907AWT1G, NSVMMBT2907AWT1G

General Purpose Transistor PNP Silicon

These transistors are designed for general purpose amplifier applications. They are housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	-60	Vdc
Collector-Base Voltage	V _{CBO}	-60	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current – Continuous	Ι _C	-600	mAdc

THERMAL CHARACTERISTICS

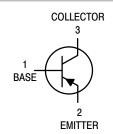
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board (Note 1) T _A = 25°C	P _D	150	mW
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	833	°C/W
Junction and Storage Temperature	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.



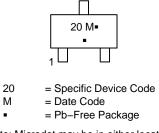
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT2907AWT1G	SC-70 (Pb-Free)	3000 Tape & Reel
NSVMMBT2907AWT1G	SC-70 (Pb-Free)	3000 Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic			Min	Max	Unit
OFF CHARACTERISTICS				•	•
Collector-Emitter Breakdown Voltage (Not $(I_C = -10 \text{ mAdc}, I_B = 0)$	e 2)	V _{(BR)CEO}	-60	-	Vdc
Collector – Base Breakdown Voltage ($I_c = -10 \text{ mAdc}, I_E = 0$)			-60	-	Vdc
Emitter – Base Breakdown Voltage ($I_E = -10 \mu Adc, I_C = 0$)			-5.0	-	Vdc
Base Cutoff Current (V _{CE} = -30 Vdc, V _{EB(off)} = -0.5 Vdc)			-	-50	nAdc
Collector Cutoff Current (V _{CE} = -30 Vdc, V _{EB(off)} = -0.5 Vdc)			-	-50	nAdc
ON CHARACTERISTICS ⁽³⁾				•	
$\begin{array}{l} \text{DC Current Gain (Note 2)} \\ (I_{C} = -0.1 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -1.0 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -10 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -150 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -500 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \end{array}$		H _{FE}	75 100 100 100 50	- - 340 -	_
Collector – Emitter Saturation Voltage (Note ($I_C = -150$ mAdc, $I_B = -15$ mAdc) ($I_C = -500$ mAdc, $I_B = -50$ mAdc)	2)	V _{CE(sat)}	-	-0.4 -1.6	Vdc
Base – Emitter Saturation Voltage (Note 2) ($I_c = -150 \text{ mAdc}$, $I_B = -15 \text{ mAdc}$) ($I_c = -500 \text{ mAdc}$, $I_B = -50 \text{ mAdc}$)			-	-1.3 -2.6	Vdc
SMALL-SIGNAL CHARACTERISTICS				•	•
Current-Gain – Bandwidth Product (I _C = –50 mAdc, V _{CE} = 20 Vdc, f = 100 MHz)			200	-	MHz
Output Capacitance ($V_{CB} = -10 \text{ Vdc}$, $I_E = 0$, f = 1.0 MHz)			-	8.0	pF
Input Capacitance $(V_{EB} = -2.0 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz})$	C _{ibo}	-	30	pF	
SWITCHING CHARACTERISTICS		•	-	•	
Turn–On Time		t _{on}	_	45	
Delay Time	(V _{CC} = –30 Vdc, I _C = –150 mAdc, I _{B1} = –15 mAdc)	t _d	_	10	1
Rise Time		t _r	-	40	1
Storage Time		ts	I	80	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

30

100

_

_

t_f

toff

 $(V_{CC} = -6.0 \ \text{Vdc}, \ \text{I}_{C} = -150 \ \text{mAdc}, \\ \text{I}_{B1} = \text{I}_{B2} = 15 \ \text{mAdc})$

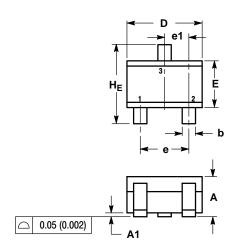
Fall Time

Turn–Off Time

MMBT2907AWT1G, NSVMMBT2907AWT1G

PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE N



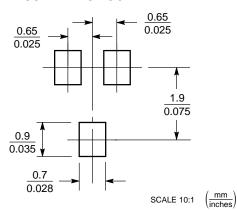
NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	м	MILLIMETERS INCHES				
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
С	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
Е	1.15	1.24	1.35	0.045	0.049	0.053
е	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC 0.026 BSC			;		
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095



SOLDERING FOOTPRINT*

A2



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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